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Three-dimensional vanadium pentoxide (V$_2$O$_5$) material architectures in the form of inverse opals (IOs) were fabricated using a simple electrodeposition process into artificial opal templates on stainless steel foil using an aqueous solution of VOSO$_4$·2H$_2$O with added ethanol. The direct deposition of V$_2$O$_5$ IOs was compared with V$_2$O$_5$ planar electrodeposition and confirms a similar progressive nucleation and growth mechanism. An in-depth examination of the chemical and morphological nature of the IO material was performed using X-ray crystallography, X-ray photoelectron spectroscopy, Raman scattering and scanning/transmission electron microscopy. Electrodeposition is demonstrated to be a function of the interstitial void fraction of the artificial opal and ionic diffusivity that leads to high quality, phase pure V$_2$O$_5$ inverse opals is not adversely affected by diffusion pathway tortuosity. Methods to alleviate electrodeposited overlayer formation on the artificial opal templates for the fabrication of the porous 3D structures are also demonstrated. Such a 3D material is ideally suited as a cathode for lithium ion batteries, electrochromic devices, sensors and for applications requiring high surface area electrochemically active metal oxides.

The growth of vanadium oxide films through electrochemical oxidation is a well-established route and the use of templates during electrochemical growth for the fabrication of three-dimensional structures is gaining increasing interest. Here, the influence of different substrates (SS, ITO, Au-coated silicon) on the electrophotropic growth of the sphere template was examined. We then compared the electrodepositional of planar non-templated films of V$_2$O$_5$ with the electrodepositional of dimensionally porous V$_2$O$_5$ inverse opals using an aqueous ethanolic solution of VOSO$_4$. The influence of the template on material growth and composition was monitored using X-ray diffraction, Raman scattering, X-ray photoelectron spectroscopy, and electron microscopy. Methods to alleviate electrodeposited overlayer formation on the artificial opal templates for the fabrication of the porous 3D structures are also demonstrated.

**Experimental**

**Opal template fabrication.—** Colloidal crystal templates were formed on ∼1 cm × 1 cm of conductive substrates of stainless steel (SS) foil, ITO/FTO coated glass of ∼2 cm × 1 cm total area, or on Au-coated silicon substrates by the electrophoretic deposition of 200 nm, 350 nm or 500 nm diameter polystyrene (PS) spheres at a constant potential of 2 V or 3 V for 30 or 50 mins. The PS spheres from Polysciences Europe GmbH were functionalized with sulfate groups to aid in self-assembly. Sphere solutions were prepared using 0.8 mL of the 2.5 wt% sulfated PS solution mixed with 4.3 mL ethanol, and ∼80 µL of 30% aqueous NH$_2$OH to ensure a pH between 8 and 10. This produced a final concentration of spheres of ∼0.4%. Electrophoretic deposition produced multilayer colloidal crystal opal PS templates with the hexagonal (111) plane grown parallel to the substrate surface, with better thickness control compared to drop-casting. Templates were then gently annealed for ∼2 h at 70°C to promote adhesion (necking of spheres) and structural stability for the subsequent electrodeposition step. Contact angle measurements were acquired for all opal templates on a Kruss Easy Drop measurement system using the static drop method.
**Electrodeposition of vanadium oxide.**—Vanadium pentoxide was synthesized by electrodeposition at room temperature using a VersaSTAT3 Potentiostat. A constant potential of 2 V was applied versus a saturated calomel (SCE) reference electrode in a three-electrode cell with a platinum mesh as counter electrode and the PS template-coated substrate as the working electrode. This is schematically outlined in Fig. 1.30,31 The electrolyte consisted of a 0.25 M VOSO₄·H₂O solution in 1:1 (v/v) mixture of deionized water and ethanol. The final solution was made by adding 2.53 g of VOSO₄·H₂O, used as purchased from Sigma Aldrich, to a mixture of 20 ml of deionized water and 20 ml of ethanol. The addition of ethanol to the solution reduces the surface tension between electrolyte and the PS template, increasing infiltration of the electrolyte to substrate surface.30,31

After deposition, samples were heated to 300°C for 24 h to remove the spheres, resulting in the formation of a network of crystalline V₂O₅. A temperature of 300°C was deemed optimum based on morphological and Raman scattering examination of the structure uniformity and crystal phase purity. For instance, heating for shorter time at 450°C resulted in regions of the opal template that were irregular and spatial inhomogeneity in oxidation state was found. The 24 h calcination period in air allowed gentler decomposition of the polymer and release of CO and CO₂ gases without rupture to the underlying porous material. The electrodeposition of vanadium oxide was performed for PS templates on ITO-coated glass, Au-coated silicon and stainless steel (SS) foil substrates. For comparison, vanadium oxide was also electrodeposited under similar conditions on to substrates without PS templates in place. These planar deposits were also heated at 300°C for 24 h to ensure the formation of crystalline V₂O₅. The mass of SS changes slightly on heating due to oxide formation, and so all SS substrates were therefore pre-heated to 300°C and allowed to cool before sphere deposition to improve the accuracy of the mass calculation. Limited thermal oxide growth (blueing) on SS post-deposition was not found to influence the adhesion of the planar or IO structures that were electrodeposited.

**Structural and elemental characterization.**—Structure and morphological characterization of the electrodeposited IO materials after sphere removal was performed using an Hitachi S-4800 field emission scanning electron microscope (FESEM). Elemental and compositional information was investigated using Raman scattering spectroscopy, X-ray diffraction (XRD), and X-ray photoelectron spectroscopy (XPS). Raman scattering was performed with a Renishaw InVia Raman Spectrometer using a 30 mW Ar⁺ laser at 514 nm excitation. The beam was focused onto the samples using a 50× objective lens and spectra were collected using a RenCam CCD camera. X-ray diffraction was performed on a Philips XPert PW3719 diffractometer using Cu Ka radiation. XPS analysis was conducted on an Oxford Applied Research Escabase XPS system using a non-monochromated Al-Ka X-ray source at 200 W. Core level scans were acquired at a take-off angle of 90° and were charge corrected with respect to the C 1s photoelectric line. A step size of 0.1 eV, dwell time of 0.5 s and pass energy of 20 eV averaged over 50 scans was used. A Shirley background correction was employed and peaks were fitted to Voigt profiles using CasaXPS software.

**Results and Discussion**

**Opal template electrophoretic deposition.**—Electrophoretic deposition of thick opal films using 350 nm spheres at 2.0 V for 30 mins produced very well ordered fcc arrangements with very few cracks, as seen in Fig. 2a. Cracking during drying of opal films is exacerbated by ordering defects or vacancies in lateral and vertical sub-structure. Previous work has identified the influence of deposition time at a given voltage, for opal template formation.32 Additional deposition approaches involving white noise during dip-coating methods,13,32,33 spin-coating techniques34 or other assembly approaches to minimize crack formation have been reasonably successful.33,35–38 We have found that an increase in voltage to 2.5 or 3.0 V does affect or-dering on a SS substrate (Figs. 2b and 2c), while deposition at 2.0 V on other conducting substrates such as ITO (Fig. 2d) and Au-coated Silicon wafers (Fig. 2f) results in lower crack density, but greater order-defect density. Thus, a higher number of ordered domains are found on ITO and Au-coated silicon after formation at 2.0 V, but much fewer macroscale cracks are observed. Contact angle measurements in
Fig. 2 confirm that the top surface of the sphere assemblies in all cases is relatively uniform and a high (>75°) water contact angle is maintained. The square packing of the spheres is found to be a characteristic of electrophoretic opal formation and more prevalent at higher voltages, and with smaller sphere sizes at the same voltage (not shown). This arrangement is indicative of a domain with (100) orientation at the surface interspersed with domains of dominant (111) orientation. On ITO and SS surfaces (which tend to be more hydrophilic than Au-coated Silicon), defects in the packing order without sphere vacancies, result in domain boundary formation in otherwise tightly packed opal template deposits.

**Chronoamperometry**—In order to compare the growth and nucleation characteristics of the templated and non-templated electrodedeposited material, chronoamperometric current-density-time transients were recorded throughout the electrodeposition process. Current density-time curves for a 3D template and planar substrate electrodeposition are shown in Figs 3a and 3b at a constant voltage of 2.0 V for 15 mins. In both depositions the current initially rises from a non-zero value due to instantaneous nucleation as the size and/or number of growth nuclei increases, thus expanding the electroactive surface area (and interstitial volume fraction in the opal) and electrode screening by the spheres. In a simple diffusion controlled process, the Cottrell equation, can be used to describe the current-time relationship and in certain cases determine a value for the diffusion coefficient, where is the current, is the number of electrons transferred, is Faradays constant, is the area of the electrode, is the concentration of the electroactive species, is the deposition time and is the diffusion coefficient for the species.

This value corresponds to the subsequently nucleated and grown on the already formed from the initial polarization and electrodeposition on to the available substrate surface. To account for cracks, domain boundary defects, and some (100) packing in opal ordering (thus increasing accessible volume in some cases), this value is taken as a lower bound value. A deposition according to:

\[
2VO^{2+} + 3H_2O \rightarrow V_2O_5 + 6H^+ + 2e^- 
\]

is also assumed and therefore the number of electrons involved in the half-cell reaction (in Eq. 1) is considered to be 2. The electrolyte used here typically had a pH ~ 2.2 at room temperature. By comparison with Potiron et al., the final phase formation is not analyzed here through a 4-electron process whereby precipitation of the insoluble intermediate species occurs if the pH is considerably higher than 1.8, according to:

\[
10VO^{2+} + 18H_2O \rightarrow H_2V_{10}O_{28}^{4-} + 34H^+ + 10e^- 
\]

\[
H_2V_{10}O_{28}^{4-} + 4H^+ \rightarrow 5V_2O_5 + 3H_2O 
\]

The total deposition time and electrolyte volume prevent significant acidification of the electrolyte.
In the electrodeposition process, the trends observed for both the templated (Fig. 3a) and planar (Fig. 3b) V$_2$O$_5$ confirm a diffusion-controlled growth. The Cottrell equation (Eq. 1) can be applied to the decreasing portion of the $i$ vs $t$ transients for electrodeposition (c) into a PS template on stainless steel and (d) onto bare stainless steel. All electrodeposition was conducted at 2 V for 15 mins. SEM image for (e) planar V$_2$O$_5$ electrodeposited film and (f) the IO deposit.

![Figure 3. Characteristic current (I) versus time chronoamperograms observed for deposition (a) into a PS sphere template on stainless-steel foil substrate and on to (b) bare stainless-steel foil and current (I) versus $t^{-1/2}$ for the decreasing portion of the $i$ vs $t$ transients for electrodeposition (c) into a PS template on stainless steel and (d) onto bare stainless steel. All electrodeposition was conducted at 2 V for 15 mins. SEM image for (e) planar V$_2$O$_5$ electrodeposited film and (f) the IO deposit.](image)

and $\sim 21.3 \times 10^{-3} \text{A} \cdot \text{s}^{1/2}$ for the bare substrate, and factoring the effective interstitial volume fraction $V_f = 0.26$, of an (infinitely thick) fcc opal available to the ions, the diffusion constants $D_{\text{fcc}} = 5.21 \times 10^{-7} \text{cm}^2 \text{s}^{-1}$ and $D_{\text{soln}} = 4.25 \times 10^{-7} \text{cm}^2 \text{s}^{-1}$ are found to be similar.

Here, $D_{\text{fcc}}$ is related to the diffusion coefficient of the VO$^{2+}$ species diffusing toward a planar electrode, $D_{\text{soln}}$, by the relationship

$$D_{\text{fcc}} = \frac{V_f}{\tau} \frac{D_{\text{soln}}}{V_f}$$

where $V_f$ is defined above and $\tau$ is the tortuosity of the diffusional path of ions through the non-linear interstitial voids of the opal template lattice, as depicted in Fig. 3a. We assume for the following analysis that the maximum packing is achieved for a (111)-oriented surface of an fcc opal and that initially, the flux of all ions is toward the substrate via the nominal electric field, but from the top and sides of the opal since it is soaked in electrolyte. From geometric considerations, it is generally accepted that conformal growth within a fcc artificial opal creates air pockets occupying $\sim 3.5\%$ of the remaining space, i.e. maximum possible infilling is $\sim 96.5\%$. This limitation is overcome since the infilling is not a sphere-surface conformal coating, but a bottom up complete infill. The tortuosity in opals was previously examined in numerical simulations and shown to be anisotropic and to vary with lattice direction, such that the rate of molecular transport normal to the (111) plane is $\sim 10\times$ less than diffusion in the bulk electrolyte. The tortuosity had a value of $\tau = 3.0$ based on finite element simulations of molecular transport through (100), (110) and (111) lattice vectors of an opal. However, this analysis assumed that the electrolyte ion approach each of these planes solely; any opal with a (111) surface will also have dissimilar cross-sectional lattice faces. Additionally, as Newton et al. confirm, the void fraction tends to 0.26–0.28 for all three low index planes (particularly (111)) when opals comprising more than 10 layers are used, which satisfies our experimental electrochemically deposited opals (that comprise several tens of sphere in thickness and also in width). We chose the estimation of comparative diffusivities of electroactive species to examine the effect of electrode surface coverage and tortuosity of the opal on the electrodeposition at a constant voltage. This avoids variation in the growth mechanism at different voltages in voltammetric analyses of diffusion in the framework of the Randles–Ševčík relation as a function of potential scan rate. Using the Eq. 5, the experimental measured tortuosity is just $\tau = 0.21$, an order of magnitude less than previously estimated. As the effective diffusion constants above are very similar, the opal thus does not significantly limit ionic diffusion in a well-soaked maximally packed fcc opal. The ratio of measured currents in the diffusional regime (via slopes of Figs 3c and 3d) is $\sim 0.22$. Thus, electrodeposition of vanadium oxide inverse opal reported here is not limited by the packed structure of the opal template and the nucleation and growth mechanism follows that of planar electrodeposition. The reduced currents scale with the reduction in available free volume of the packed structure.

**Structure of electrodeposited V$_2$O$_5$ inverse opals.**——The bottom-up filling of the sphere template can be advantageous and useful in preparing IOs. Material congestion in the upper layers of the template tends to be problematic in some approaches where top down infilling is used, particularly those involving liquids or solutions that need to wet the entire active 3D porous surface. For instance, atomic layer deposition infilling of opal templates has recently been adopted to facilitate conformal filling of interstitial spaces within the template with functional materials. Electrodeposition of structured materials within templates using the parameters reported here facilitates complete bottom-up infilling via continuous nucleation and growth. However, effective nucleation and coverage of the initial bare surface is critical for good electrical contact for subsequent use and to prevent delamination during drying by anchoring the full inverse opal to the electrode surface. This approach offers a facile and improved infilling method that does not necessitate vacuum infiltration for liquid-based precursors, and thicker deposits, volumetric densities are therefore possible and controllable with electrodeposition.
The bottom-up approach provides other challenges which are also investigated. Electrodeposited material formation in IOs or other porous material templates can also occur at the surface of the template i.e. those areas of the substrate in contact with electrolyte by a preferential nucleation mechanism. At lower current densities, issues due to discontinuous infilling are well known, and at current densities that promote continuous material infilling, a thick, sealing overlayer of the material on the template surface can often form. When using a sphere template atop a conductive substrate the available electrode surface are interstitial sites within the opal template and in the preferred case, growth and nucleation continues around and within the template.\textsuperscript{50,51} It is possible however, for growth to occur parallel to the substrate beneath the regions occupied by the template. In such cases, this deposition may reduce template adhesion leading to separation from the substrate before complete electrodeposited infiltration of the entire template. Detachment from the substrate is also seen when material thickness grows to a large mass, effectively pulling the template from the substrate. In this work, this effect was particularly prevalent for depositions of \( \geq 1 \) h (corresponding to a 3D IO structure thickness \( \geq 18 \) \( \mu \text{m} \)) on all conductive substrates investigated. Deposition time must therefore be calibrated to suit the template thickness. Excessive deposition times at the same voltage results in an overfilling of the template, producing a porous IO material can be indexed to the orthorhombic structure of crystals, as shown for samples on ITO-coated glass in the SEM images in Figs. 4a and 4b.

To reduce the possibility of template overfilling and/or detachment from the substrate, deposition times were restricted to 15 min. Electrophoretically deposited template formed at 3 V for 30 min, are usually infilled to a level just below the total template thickness (see Fig. 4c) after 15 min, leaving several layers of spheres in the template surface visible after removal from the electrolyte. In this way, completely infilled, open IO structures that are more conducive to electrolyte infiltration were formed with thickness of \( \sim 10–12 \) \( \mu \text{m} \), shown in the cross sectional SEM image in Fig. 4d. The uninfilled opal layers at the top of the template are thus sacrificed to ensure an open topped 3D inverse opal. By preventing complete infiltration, nucleation and continued growth of the overlayer is prevented using electrodeposition parameters that are preferential to infilling from the substrate upwards.

The two central morphologies observed in an IO structure formed at 2 V for 15 min on SS foil are presented in Figs. 4e and 4f. SEM analysis revealed the formation of three-dimensional macroporous structures separated into an island like arrangement by structural voids characteristic of crack propagation and material contraction that occurs during sphere removal and sample drying.\textsuperscript{52,53} Networked material closest to the centre of the template appeared more disordered (Fig. 4e) than those formed near the electrolyte meniscus line and outer edges of the sample, which maintained the structural order of the opal template (Fig. 4f). It is unclear whether the disorder within the sample structure is as a result of the deposition process or as result of sphere removal. At regions along the meniscus, template thickness is often thinner than the template bulk due to a thin liquid region within a meniscus, thus reducing the density of spheres available for deposition during EPD as well as overall solution settlement during the process. It could be speculated that the disruptive removal of the uninfilled layers of spheres causes the surface disorder in the centre regions of the IO compared with the edge areas. Accurate filling of a self-assembled opal template of indeterminate thickness (or variable thickness) may require further work for accurate control of electrodeposition kinetics and time.

**Crystallinity and phase purity of electrodeposited V\(_2\)O\(_5\) inverse opals.**—Raman scattering spectra were measured for the electrodeposited IO material and the material deposited without an opal template after heating to 300°C for 24 h. The Raman spectra for the IO material can be indexed to the orthorhombic structure of crystalline V\(_2\)O\(_5\) with a space group \( Pmmn \) and \( D_{2h} \) point symmetry. The characteristic Raman modes of crystalline orthorhombic V\(_2\)O\(_5\) at 102, 145, 196, 285, 304, 404, 482, 526, 701, and 994 cm\(^{-1}\) are observed. The stretching mode associated the short vanadyl V=O bond,\textsuperscript{24} of bond length 1.58 Å, is well defined at 995 cm\(^{-1}\), and the vibration associated with the layered nature of V\(_2\)O\(_5\) at 145 cm\(^{-1}\) is the most prevalent. Raman scattering data taken from the material deposited without a template before heating is shown in Fig. 5a. The spectrum resembles that of the IO V\(_2\)O\(_5\) material but with broader peaks at much lower intensities with some variation in peak position. The broadness of the peaks, particularly the V-O-V stretching vibrations between 280–750 cm\(^{-1}\) illustrates the predominately amorphous nature of the as-deposited material. The poorly defined peak at 990 cm\(^{-1}\) and the peak at wavenumber 1019 cm\(^{-1}\) are associated with the V=O vanadyl stretching vibration. The higher ionic radius of V\(_{4+}\) accounts for a higher bond length than that of

![Figure 4. SEM images of the V\(_2\)O\(_5\) IO structure after infilling of PS sphere templates on ITO-coated glass by electrodeposition at 2 V showing (a) and (b) the excess material atop the IO structure from an extended infill time of 1 h. Cross sectional SEM images of (c) a PS template on stainless steel substrate infilled at 2 V for 15 min before removal of the spheres, indicating only a partially filled template with a remaining area of unfilled sphere layers at the top (above white dashed line) and (d) the IO structure after removal of the spheres and material crystallization for \( \sim 24 \) h at 300°C. (e) SEM images of the disordered but highly porous IO network observed at regions near the centre of the sphere template and (f) the better ordered areas near the top and side edges for a sample on SS foil.](image)
V$^{5+}$ leading to a lower vibrational frequency, therefore the peak at 990 cm$^{-1}$ corresponding to a bond length of 1.60 Å can be attributed to V$^{4+}$ and the peak at 1019 cm$^{-1}$ with bond length 1.58 Å to V$^{5+}$.56,57 Such peaks have also been observed in V$_2$O$_5$ hydrated xerogels and their respective positions above and below the standard frequency for the V$^{5+} = O$ vibration of crystalline V$_2$O$_5$ (usually ~995 cm$^{-1}$) attributed to the effect of crystal water molecules within the van der Waals layer spacing of the V$_2$O$_5$ matrix material.58 The low intensity and broadness of these peaks in the as-deposited spectrum generally is attributed to the low crystallinity and predominant amorphous phase of the as-deposited material.16,59 Heating of the as-deposited material reduces the level of hydration and oxidizes the V$^{4+}$ ions to V$^{5+}$ creating a single vanadyl stretching vibration peak corresponding to a short bond length of approximately 1.58 Å.

The XRD pattern (Fig. 5b) obtained for the electrodeposited IO structure (red pattern) resembles that of bulk crystalline V$_2$O$_5$, with the (001) peak at 20 = 20.37° and corroborates the classification of the material as orthorhombic V$_2$O$_5$ with space group P$mnm$. No clear XRD pattern was obtainable from the as-deposited (with or without template) material due to its predominantly amorphous nature. However, after heating for 24 h at 300°C the as-deposited material (black pattern) produced a well-defined pattern indicative of crystalline orthorhombic V$_2$O$_5$. Calcination removal of spheres by this method is effective and no remnant PS is found. Additionally, the crystalline quality is excellent, and effective removal of the entire template through the brittle IO material is possible at temperatures just above the decomposition temperature for PS.

![Figure 5](image1.png)

**Figure 5.** (a) Raman scattering data for the IO material (red) and the as-deposited material (black) (b) XRD spectra for the inverse opal material (red) and the as-deposited material (black) once it is heated to 300°C for 24 h compared with the orthorhombic V$_2$O$_5$ reference spectrum (line graph). SS indicates diffraction peaks from the stainless steel substrate.

The marked intensity difference from (001) reflection for the heated as-deposited material compared with the IO material can be attributed to the differences in nanostructure of the as-deposited thick films compared with the porous nano-walled IO structure. The nanoscale sub-structure of the walls of the crystalline IO limit the intensity of reflections from the characteristics (001) interlayer spacing of orthorhombic V$_2$O$_5$. In such structures, the Scherrer relation provides an estimate of the effective crystallite size $L = 0.94\lambda/\beta \cos \theta$ where $\lambda$ is the X-ray wavelength (1.54 Å), $\beta$ is the line broadening or FWHM (in this case of the (400) peak), and $\theta$ = the Bragg angle. An average crystallite size $L$ of ~20–25 nm for the nanoscale crystalline sub-structure of the IO material within the walls of the IO, and correspondingly, ~90–100 nm for the heated as-deposited film.

XPS measurements were carried out to compare the as-deposited material before and after heating on the bare substrate to the IO V$_2$O$_5$ obtained after heating at 300°C for 24 h to crystallize and remove the spheres, and the core level spectra are shown in Fig. 6. The color of the as-deposited V$_2$O$_5$ is typically dark green/black while the IO material exhibits a bright yellow color, the as-deposited material has a dull yellow or red-brown appearance once heated to 300°C for 24 h, and these characteristic colors are symptomatic of a variation in oxidation state or level of hydration in the materials. Note, these
colors do not have a angle-dependent structural color contribution in their description from neither 2D Bragg (grating) diffraction nor 3D pseudo photonic bandgap from the IO – the colors are correlated to the materials’ oxidation states.

In general, the XPS results corroborate both Raman and XRD data, confirming both the IO and as-deposited materials, as V2O5. The V 2p3/2 core-level photoelectron peak corresponding to the presence of V+5 appears at ~518 eV for the as-deposited material electrodeposited onto the bare substrate (Fig. 6a) while the V 2p3/2 core level emission for the as-deposited film of V2O5 on IO is found at ~518.5 eV after 24 h at 300 °C (Fig. 6b); details are summarized in Table I. This V 2p3/2 core level emission shifts to ~517.9 eV for the electrodeposited IO material (Fig. 6c). The V 2p3/2 core level occurs at similar energies for the IO material (525.3 eV) and for the material deposited without a template both before (525.4 eV) and after heating (526.6 eV).

The O 1s emission consists of two components in all three cases, at binding energies of 532.6 and 530.7 eV for the as-deposited material, at ~532.4 and 530.9 eV for the as-deposited material and at ~532.3 and 531.1 eV for as-deposited material heated to 300 °C for 24 h in both cases, corresponding in all three cases to oxygen ions in the V−2O−6 and V−2O−5 groups, respectively. The oxidation states determined from the V 2p and O 1s core-levels can be estimated according to 13.82 – 0.68 [O 1s − V 2p3/2] [28,30] The average vanadium oxidation state was calculated to be 4.912 for electrodeposited IO structure, and 5.116 (thus V5+) for the non-templated planar V2O5 film. Thus, electrodeposition allows the formation of crystalline V2O5 with orthorhombic layered structure and a dominant pentavalent oxidation state [62]. Electrodeposited IO V2O5 retains predominantly monovolatile structure as a crystal and within the surface phase even in a structure with a much greater surface area, which typically exhibit di- or multivalent character.

**Conclusions**

This work illustrates a route for the fabrication of high quality, open 3D crystalline V2O5 inverse opal on several conductive substrates by electrodeposition using a aqueous solution of VO(V)O3·xH2O and electrophoretically deposited artificial opal templates. Opal templates are uniformly deposited on each of the conductive substrates, and high quality opal films are formed using 350 nm PS spheres at 2.0 V. Through chronocomparmenty, electron microscopy, X-ray diffraction and photoelectron spectroscopy, the growth and formation of the V2O5 IO material was compared in detail with as-deposited planar electrodeposited V2O5 films deposited without an artificial opal template. Analysis of chronocomparmenty polarization confirms a progressive nucleation mechanisms for V2O5 electrodeposition on planar as well as artificial opal-templated surface. Electrodeposition facilitates the fabrication of a bulk-like, single crystalline monovolatile V2O5 phase via electrodeposition at a nanoscale length scale with complete coverage of the substrate and conformal template infilling. The influence of ionic mobility retardation due to opal template tortuosity, and coverage of the conducting substrate with the template, was demonstrated to be negligible. Electrodeposition of an IO is a function of the internal interstitial volume once conditions for conformal nucleation and continued growth are met. A strategy to successfully avoid overlayer growth was demonstrated, involving electrodeposition infilling (conformal from the bottom up) several sphere lengths short of the top surface, leaving an open tapered 3D inverse opal without an overlayer. This type of structure and material is suitable for use in lithium ion battery cathodes to facilitate improved ionic diffusion and electrolyte infiltration and shorter solid state diffusion lengths, and allow the incorporation of secondary active phases within the porous regions through sequential (electro)deposition methods, and many other uses. Electrodeposited IO structures may also provide active materials for gas sensing, electro and thermochromics materials on a range of current collectors, substrates and surfaces.

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